Table S1 Effects on substrate-binding interaction of different Ssa1p mutations

Mutation	RMSD (nm) ^a	Interaction energy (kJ mol ⁻¹) ^b	Hydrogen bonds ^c	Hydrophobic interactions ^c	Distance of arch structure residues (nm) ^d	Number of hydrogen bonds between inner loops ^d
WT	0.291	-324.725	3.286	61.952	0.778	2.873
L483W	0.265	-472.013	6.714	73.571	0.582	2.444
L483A	0.265	-404.898	3.714	56.333	0.832	2.779
L483H	0.232	-518.677	7.048	87.047	0.664	2.944

^aRMSD of Cα atoms in the stabilized MD structure.

^bInteraction energy calculated during the SMD

^cNumbers of hydrogen bonds and hydrophobic interactions during the course of the SMD.

^dDistance of arch structure residues and hydrogen bonds in between inner loops in stabilized MD structure.